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the state of the s		partment of Commerce at and Trademark Office	Atty Docket 0756-229	Serial No. 09/837,877			_
'INFORMATION DISCLOSURE STATEMENT		Applicants: Shunpei YAMAZAKI et al.					
APR	1 5 2002 🖫		Filing Date: April 19, 2001		Group Art Unit: N/A		
PAT	, E	FOREIGN PATEN	IT DOCUMENTS		-		
Examiner Initial	RADEM Socument Number	Date	Country	Class	Subclass	<u>Translation</u> Yes N	
MU	11-354802	12/24/1999	JP			Full Eng	
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Date Considered

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Form PTO-144 (Rev. 8-83)	9	epartment of Commerce nt and Trademark Office	Atty Docket 0756-2 Serial No		Serial No. 0	. 09/837,877	
MENTION DISCLOSURE STATEMENT		Applicants: Shunpei YAMAZAKI et al.					
Mile 1 3 20 ²³		Filing Date: April 19, 2001		Group Art Unit: Not			
M AM	\$*/	U.S. PATENT	DOCUMENTS Assigned				
xaminer nitial	T& TRADE Document Number	Date	Name	Class	Subclass	Filing Date	
M	4,609,930	09/02/1986	Yamazaki				
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mC	5,034,788	07/23/1991	Kerr				
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WU	5,124,769	06/23/1992	Tanaka et al.				
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INFORMATION DISCLOSURE STATEMENT		Applicants: Shunpei YAMAZAKI et al.					
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Examiner Initial	Document Number	Date	Name	Class	Subclass	Filing Da	
1	3 6,252,248	06/26/2001	Sano et al.				
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	02-015676	01/19/1990	JP			Eng Abst	
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INFORMATION DISCLOSURE STATEMENT		Applicants: Shunpei YAMAZAKI et al.				
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Examiner/		Date Considered 7/26/09.				
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